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Journal or publication title: Physical review B
Volume: 67
Number: 3
Page range: 035102
Year: 2003

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URL: http://hdl.handle.net/2241/88573
doi: 10.1103/PhysRevB.67.035102
Far-infrared phonon-polariton dispersion probed by terahertz time-domain spectroscopy

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(Received 18 June 2002; published 6 January 2003)

We report observations of the intensity and phase transmission spectra related to phonon-polariton propagation using coherent far-infrared radiation for a high-quality ferroelectric bismuth titanate crystal plate. In order to determine the polariton-dispersion relation, the phase delay was determined minutely as a function of the THz radiation frequency in the region between 3 and 100 cm$^{-1}$. The anisotropy of polariton dispersion relation was also successfully determined on the $c$ plate simply by switching the polarization direction of an incident beam from $E_{//a}$ to $E_{//b}$. The observed polariton dispersion relations are consistently reproduced by the calculation using Kurosawa’s formula.

DOI: 10.1103/PhysRevB.67.035102

PACS number(s): 78.47.+p, 71.36.+c, 77.84.Dy

I. INTRODUCTION

Dielectric properties of terahertz (THz) regions are of great importance due to the rich physical and chemical properties in this range. Very recently the generation of coherent THz radiation by a femtosecond pulse laser has enabled the very promising technique of THz time-domain spectroscopy (THz-TDS).$^{1–4}$ This technique has a better signal-to-noise ratio at frequency below 100 cm$^{-1}$ than conventional far-infrared Fourier transform spectroscopy. It is based on ultrashort THz electromagnetic (EM) pulses, which are generated and detected by small photoconductive antennas driven by femtosecond laser pulses. This time-gaged coherent nature makes it possible to determine not only the transmission intensity but also its phase delay accurately. Furthermore, unique applications for dispersion relations for various excitations have become possible. In fact, for a photonic crystal, by measuring the phase delay as a function of radiation frequency, Wada and co-workers recently succeeded in determining the polariton-dispersion relation, determined from the phase delay, is consistently interpreted by taking account of phonon-polariton propagation in the crystal.

In this paper, we report on a measurement of the intensity and phase of complex transmission using THz-TDS for a ferroelectric bismuth titanate crystal, which is a key material in ferroelectric memories. We then show that this nonlinear dispersion relation, determined from the phase delay, is consistently interpreted by taking account of phonon-polariton propagation in the crystal. The observed dispersion relation is in a good agreement with the calculated one.

II. EXPERIMENT

The sample used was a thin $c$-plate of a flux-grown bismuth titanate $\text{Bi}_4\text{Ti}_3\text{O}_{12}$ (BIT) single crystal with the area of $15\times15\text{mm}^2$ and a thickness of $d=0.23$ mm. Since the cleavage perpendicular to the $c$ axis is very strong, like mica crystals, very flat cleaved surfaces were used for measurements. The THz time domain spectrometer used$^5$ is shown in Fig. 1. To reduce the absorption by water vapor, all the optics and the sample were placed in a vacuum chamber. Femtosecond pump pulses with a wavelength of 780 nm and a power of 20 mW were generated by a mode-locked compact fiber laser with a repetition rate of 80 MHz. The pump pulses were focused by an object lens onto the biased gap of the photoconductive antenna made of low-temperature grown GaAs. The emitted THz radiation was collimated and focused by a pair of off-axis paraboloidal mirrors onto the sample. The spot size of the THz beam on the sample is about 2 mm in diameter. The signals transmitted from the
sample were collimated again, and focused by another paraboloidal mirror onto a detector of a GaAs photoconductive antenna. The received signals were gated using incident pulses. An ammeter was used to measure the dc photocurrent induced by the transmitted radiation field from a sample. The waveform of transmitted EM pulses was determined by changing the delay time. The total acquisition time is 1 hour and the number of scan is 30.

III. RESULTS

BIT is one of the most important key materials in ferroelectric memories. BIT has a monoclinic-layered perovskite structure with the point group $m$ at room temperature. It undergoes a ferroelectric phase transition at 675 °C, and a high-temperature paraelectric phase is tetragonal with the point group 4/mmm. The direction of spontaneous polarization is inclined at a small angle of about 4.5° toward the monoclinic $a$ axis in the $a$-$c$ plane. The $a$- and $c$-axis components of the spontaneous polarization are 50 and 4 $\mu$C/cm$^2$, respectively. In the ferroelectric phase, the displacive nature was observed with the underdamped soft optic mode at 28 cm$^{-1}$ and at room temperature. Regarding optical phonon modes, $A'(x,z)$ and $A''(y)$ modes are both infrared and Raman active where the mirror plane is perpendicular to the $y$ axis. The soft optic mode has an $A'(x,z)$ symmetry where the coordinate $z$ is parallel to the $a$ axis.

Transmission spectra of the $c$ plate of BIT were observed at room temperature by using THz-TDS. $A'(x,z)$ and $A''(y)$ modes are active when the light polarization is parallel to the $a$ axis ($E\parallel a$) and $b$ axis ($E\parallel b$), respectively. First, the time-domain THz signal for the polarization $E\parallel a$ was recorded as shown in Fig. 2. Second, this signal was converted into the frequency-domain power and phase, as shown in Fig. 3. Third, the transmission power was normalized by the reference one without the sample to be measured. The same procedure was carried out for the polarization $E\parallel b$. Figures 4(a) and 4(b) show the frequency dependence of transmission intensity and phase delay ($\phi/2\pi$) in a range between 3 and 100 cm$^{-1}$ for $E\parallel a$ and $E\parallel b$, respectively. It is found that $\phi$ vs $\omega$ shows nonlinear behavior near the gap edges at TO and LO.

FIG. 1. Experimental setup of the THz time domain spectrometer.

FIG. 2. The time-domain THz signals for the polarization $E\parallel a$. 
mode frequencies. The increase of the gradient in the phase delay at the edges indicate the slowing of group velocity which is reasonable for the propagation of phonon-polariton. In order to determine the phonon-polariton dispersion relation, we calculated the wave vector $k_v$ of the phonon-polariton from the phase delay using the equation

$$\phi = k_v \frac{v}{c} \Delta \phi,$$

where $c$ is the light velocity. Thus the dispersion relations were obtained as shown in Figs. 5~a and 5~b. For the polariton dispersion, $c^2 k_v^2 / \omega^2 = \varepsilon(\omega)$. When the damping of phonon was negligible, a factorized form of $\varepsilon(\omega)$ was derived by Kurosawa. Consequently, the polariton-dispersion relation is given by

$$\frac{c^2 k_v^2}{\omega^2} = \varepsilon(\omega) = \varepsilon(\infty) \prod_{i=1}^{N} \frac{\omega_{\text{LO}}^2 - \omega^2}{\omega_{\text{TO}}^2 - \omega^2}. \quad (1)$$

Since the measured frequency is below 100 cm$^{-1}$, we used the following approximation to fit the data:

FIG. 3. The frequency-domain power and phase for the polarization $E \parallel a$.

FIG. 4. Transmission intensity and phase shift spectra of the ferroelectric bismuth titanate crystal on the $c$ plate for the polarization along (a) the $a$ axis and (b) the $b$ axis. Closed and open circles denote the transmission intensity and phase shift, respectively.

FIG. 5. Dispersion relations of phonon-polariton for a $c$-plate bismuth titanate crystal for the polarization along (a) the $a$ axis and (b) the $b$ axis. Closed circles denote observed values, and solid lines are calculated curves using Eq. (2).
The observation of low-frequency polariton below 100 cm$^{-1}$ produced such as impulsive stimulated Raman scattering (ISRS) measurements on LiTaO$_3$ and LiNbO$_3$ resulted in conflicting results. In BIT, the polariton branches were separately observed down to 3 cm$^{-1}$. For the two directions, two different low-frequency branches, whereas no such splitting is observed here. Concerning splitting in the low-frequency polariton direction, for light polarization parallel to the $a$ axis ($E\|a$) and the $b$ axis ($E\|b$), we studied $\varepsilon_{\alpha}(\omega)$ and $\varepsilon_{\beta}(\omega)$, respectively. For the two directions, two different low-frequency polariton branches were separately observed down to 3 cm$^{-1}$. The solid curves in Figs. 5(a) and 5(b) denote the curves calculated by Eq. (2) using mode frequencies of $A'(x,z)$ and $A''(y)$ symmetries, respectively. There was good agreement between the observed and calculated polariton-dispersions. Therefore, it is concluded that this nonlinear relation reflects the dispersion relation of bulk phonon-polariton. Table I shows the values of fitting parameters for observed polariton-dispersions.

<table>
<thead>
<tr>
<th>$\omega$</th>
<th>$\varepsilon(1)$</th>
<th>$\varepsilon(0)$</th>
<th>$A'(x,z):E|a$</th>
<th>$A''(y):E|b$</th>
</tr>
</thead>
<tbody>
<tr>
<td>LO1</td>
<td>28.0 cm$^{-1}$</td>
<td>6.76</td>
<td>36.0 cm$^{-1}$</td>
<td>6.76</td>
</tr>
<tr>
<td>TO1</td>
<td>32.5 cm$^{-1}$</td>
<td>49.0</td>
<td>42.0 cm$^{-1}$</td>
<td>8.10</td>
</tr>
<tr>
<td>LO2</td>
<td>68.0 cm$^{-1}$</td>
<td>58.4</td>
<td>85.0 cm$^{-1}$</td>
<td>6.76</td>
</tr>
<tr>
<td>TO2</td>
<td>74.5 cm$^{-1}$</td>
<td>79.2</td>
<td>98.5 cm$^{-1}$</td>
<td>149.0</td>
</tr>
</tbody>
</table>

$$k(\omega) = \frac{\sqrt{\varepsilon(1)}}{\varepsilon(\omega)} \frac{2}{\omega} \prod_{i=1}^{3} \left( \frac{\omega_{\alpha}^{2} - \omega_{\alpha}^{2}}{\omega_{\beta}^{2} - \omega_{\beta}^{2}} \right)^{1/2}, \quad (2)$$

where we renormalize the contribution of the modes $i=3$ to the fitting parameter $\varepsilon(1)$, as given by

$$\varepsilon(1) = \frac{\varepsilon(\omega)}{\varepsilon(\omega)} \prod_{i=3}^{N} \frac{\omega_{\alpha}^{2} - \omega_{\alpha}^{2}}{\omega_{\beta}^{2} - \omega_{\beta}^{2}}. \quad (3)$$

In BIT, $\varepsilon(\omega)$ is anisotropic and depends on the polarization direction. For light polarization parallel to the $a$ axis ($E\|a$) and the $b$ axis ($E\|b$), we studied $\varepsilon_{\alpha}(\omega)$ and $\varepsilon_{\beta}(\omega)$, respectively. For the two directions, two different low-frequency polariton branches were separately observed down to 3 cm$^{-1}$. The solid curves in Figs. 5(a) and 5(b) denote the curves calculated by Eq. (2) using mode frequencies of $A'(x,z)$ and $A''(y)$ symmetries, respectively. There was good agreement between the observed and calculated polariton-dispersions. Therefore, it is concluded that this nonlinear relation reflects the dispersion relation of bulk phonon-polariton. Table I shows the values of fitting parameters for observed polariton-dispersions.

IV. DISCUSSION

Up to now, phonon-polariton has been studied mainly by forward Raman scattering experiments. The problem was the observation of low-frequency polariton below 100 cm$^{-1}$ because the intense elastic scattering causes the strong Rayleigh wings which screen the polariton peak from Raman spectra. Although the lower limit had been markedly reduced upon the use of a Raman spectrometer with the highest stray light rejection of 10$^{-14}$ at 20 cm$^{-1}$, the observation below 20 cm$^{-1}$ was still difficult. Since 1992, several different techniques for the observation of phonon-polariton were introduced such as impulsive stimulated Raman scattering (ISRS) with femtosecond laser pulses. However, ISRS measurements on LiTaO$_3$ and LiNbO$_3$ resulted in conflicting results concerning splitting in the low-frequency polariton branches,

V. CONCLUSIONS

We studied phonon-polariton by using THz-TDS. The frequency dependence of the transmission phase delay was accurately measured for a high-quality ferroelectric bismuth titanate crystal. The obtained phonon-polariton dispersion relation was well reproduced using the calculation based on Kurosawa's formula. The lowest branch of phonon-polariton dispersion was determined down to the very low frequency of 3 cm$^{-1}$, which cannot be attained by other optical experimental methods, especially for extraordinary polaritons. Therefore, we believe that this is the first observation of the dispersion relation of phonon-polariton in the far-infrared region by THz-TDS. The anisotropy of polariton dispersion was also clearly observed simply by rotating the polarization plane of the incident beam. The present measurement also indicates the possibility of accurate determination of the damping factor of the phonon-polariton in the far-infrared region by using the $k$ dependence of transmission and reflection amplitude.

ACKNOWLEDGMENTS

We thank Professor K. Sakata of Tokyo Science University for providing the bismuth titanate single crystal. This work was supported in part by the Japan Science and Technology Corporation.